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14. ABSTRACT

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RPPR Final Report

as of 09-Jan-2018

Agency Code:

Proposal Number: 58398ELPCS

Agreement Number: W911NF-12-1-0025

INVESTIGATOR(S):

Name: Michael Scott Arnold
Email: msarnold@wisc.edu
Phone Number: 60826238630000
Principal: Y

Organization: **University of Wisconsin - Madison**

Address: The Board of Regents of the University of Wisconsin Sys, Madison, WI 537151218

Country: USA

DUNS Number: 161202122

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Report Date: 09-Apr-2016

Date Received: 08-Jan-2018

Final Report for Period Beginning 10-Jan-2012 and Ending 09-Jan-2017

Title: Precision Controlled Carbon Materials for Next-Generation Optoelectronic & Photonic Devices

Begin Performance Period: 10-Jan-2012

End Performance Period: 09-Oct-2017

Report Term: 0-Other

Submitted By: Michael Arnold

Email: msarnold@wisc.edu

Phone: (608) 262-38630000

Distribution Statement: 1-Approved for public release; distribution is unlimited.

STEM Degrees: 3

STEM Participants: 7

Major Goals: From original proposal:

“Carbon nanotubes and graphene-based semiconducting materials exhibit exceptional properties and behaviors and unique physical phenomena that make them highly attractive for next-generation optoelectronic and photonic devices. Overall, in this project, we are building on our group’s unique abilities for creating precision-controlled carbon semiconductors and exploiting their exceptional characteristics to engineer next-generation carbon-based optoelectronic and photonic devices with superior performance and capabilities. These devices include carbon nanotube-based photovoltaic, photodetector, and light emitting devices, which build on our capabilities for creating highly monodisperse electronic-type-controlled and bandgap-controlled semiconducting nanotubes [1-3], as well as preliminary demonstrations of carbon nanotube donor/acceptor heterojunction diode devices in which the nanotubes are the light absorbers[3-7]. These devices also include semiconducting graphene optoelectronic and photonic devices, which build on our capabilities for creating structure-controlled nanopatterned graphene with tunable, semiconducting behavior and with refined edge structures [8-11]. Overall, work focuses on the study of materials’ optoelectronic and photophysical properties and new fundamental concepts in devices that exploit the exceptional properties of these nanocarbon materials.”

Accomplishments: In this project, we made breakthroughs in: (1) semiconducting carbon nanotube-based photovoltaic solar cells and photodetectors; (2) high-performance carbon nanotube electronics; (3) stretchable electronics; (4) nanostructured graphene plasmonics; and (5) polymer-nanotube conjugate chemistry.

(1) Semiconducting carbon nanotube-based photovoltaic solar cells and photodetectors

Semiconducting carbon nanotubes are attractive absorbers for photovoltaic and photodetector devices. The use of nanotubes as light absorbers is distinct from other work which has used nanotubes as optically “dead” charge acceptors and collectors to other absorbers. Semiconducting nanotubes are strong, dye-like absorbers with bandgaps tunable to the ideal for single-junction solar PV ~1.3 eV or deeper into the IR for photodetectors. Nanotubes offer strong optical absorptivity ($> 1E5$ 1/cm) and fast transport mobility ($> 1E4$ cm²/V/s). Compared to organic semiconductors, nanotubes are much more air stable. Other advantages include that nanotubes can be integrated onto arbitrary substrates, they are flexible, and they avoid complex heteroepitaxy. Prior to the project onset, we had discovered how to unlock nanotubes’ potential as photoabsorbers by pairing them with electron acceptors that overcome the ~0.2-0.3 eV exciton binding energy, including C60-fullerenes and derivatives, to form bilayered type-II donor/acceptor heterojunctions (Fig. 1).

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Support from this project resulted in:

A) A review paper co-authored by Arnold et al. on nanotube-based photovoltaics (Phys. Chem. Chem. Phys. 2013).

B) New insight into the factors affecting the efficiency of nanotube PV devices including:

-i) Disruption of exciton transport by the polymer wrapper that surrounds each tube. Reducing the coverage of this polymer by 3x leads to a 2x improvement in device external quantum efficiency (EQE) – from 22 to 43% at bandgap (Chem. Phys. 2013).

-ii) Sidewall and end defects induced by harsh processing methods that quench excitons. Replacing harsh processing methods (e.g., ultrasonication) with gentler methods (e.g., shear mixing) increases EQE from 28 to 49% (J. Phys. Chem. C. 2017; In Preparation 2017).

-iii) Interfacial defect-mediated recombination. We have learned that loss occurs via trap-limited free carrier recombination using time-resolved microwave conductivity and low-temperature current-voltage measurements (Phys. Rev. B 2015; Submitted 2017).

C) Advances in devices including:

-i) Realization of 1% solar power efficiency and 7% monochromatic power efficiency in devices incorporating nanotubes films only 5 nm in thickness, despite the fact that only a few % of the solar flux is absorbed. The peak external and internal QE at the nanotube bandgap (1055 nm) are 43% and >75%, respectively (Appl. Phys. Lett. 2013).

-ii) Demonstration of co-cast nanotube/fullerene blended heterojunction devices by using an aerogel infiltration technique, increasing the power conversion efficiency from 1.0 to 1.7% by increasing the interfacial area across which exciton-to-dissociated charge generation occurs (Small 2014).

-iii) Realization of photodetectors with peak NIR specific detectivity (D^*) of $\sim 1E12$ Jones at 1055 nm at 300K.

High internal QE has been demonstrated for thin nanotube films in PV devices, which is promising. The internal QE drops for films thicker than > 10 nm due to the poor out-of-plane exciton diffusion length of ~ 5 -10 nm, limiting external QE. Our models show that increasing this length to 100 nm (by making more pristine tubes with fewer defects) or improving the microstructure of nanotube/fullerene blends should result in dramatically more efficient PV devices (power efficiency $>10\%$). The D^* is already commercially relevant. Future optimization of detectors should proceed to understand factors that minimize dark current and maximize speed.

(2) High-performance carbon nanotube electronics

In research supported by multiple agencies, with crucial aspects supported by this award, we realized a major breakthrough in carbon nanotube electronics. We created for the first time field effect transistors (FETs) based on aligned arrays of nanotubes that outperform Si and GaAs FETs in terms of on-state current density and conductance. Conductance as high as 0.46 of the quantum conductance per nanotube was achieved. The conductance of the arrays reached $1.7 \text{ mS } \mu\text{m}^{-1}$, which was 7x higher than previous nanotube array FETs made by other methods. The saturated on-state current density was as high as $900 \text{ } \mu\text{A } \mu\text{m}^{-1}$, similar to or exceeding Si FETs compared at equivalent gate oxide thickness and off-state current density (ACS Nano 2014; Sci. Adv. 2016).

(3) Stretchable electronics

Traditional electronic and optoelectronic devices fabricated on rigid substrates are usually brittle and undeformable. There is a growing demand for devices that can flex, stretch, and harmonize with the environment and humans. Most research in this area has focused on *flexible* electronics. Much more difficult is achieving devices that are not only flexible but highly *stretchable*, enabling large changes in shape and extreme changes in size.

Support from this project resulted in (Fig. 2):

A) The development of stretchable thin film transistors (TFTs) based on carbon nanotubes. Our initial architecture employed buckled thin films of polyfluorene-wrapped semiconducting single-walled carbon nanotubes as the TFT channel, buckled metal films as electrodes, and unbuckled flexible ion gel films as the dielectric. TFTs with this initial architecture are stretchable at up to 50% uniaxial elongation without degradation in performance (Nano Lett. 2014; U.S. Patent 8,987,707 2015).

B) The development of buckled nanotube TFTs incorporating bucked ion gel gate dielectrics that are stretchable up to 90% uniaxial elongation (Appl. Phys. Lett. 2015).

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C) The development of buckled nanotube TFTs that are biaxially stretchable (J. Appl. Phys. 2017).

D) The development of stretchable nanotube TFTs that can be down-scaled to sub-10 μm channel length – a length-scale of importance for future stretchable display technologies (In Preparation 2017).

These TFTs are expected to facilitate unconventional applications in electronics and optoelectronics like implantable conformal biosensors, wearable electronic devices, and stretchable displays.

(4) Nanostructured graphene plasmonics

This project supported advances in the development of novel materials with mid-IR plasmon resonances (Fig. 3). We have shown that large-area sheets of graphene perforated by hexagonal periodic arrays of nm-scale holes with periods in the range of 24-120 nm support plasmon resonances in the range of 1700-3200 cm^{-1} , with the resonance varying as $P^{-0.5}$. These sheets can be easily fabricated using block copolymer lithography and have promise for optical biosensors because the plasmon can be coupled with the vibrational modes of nearby molecules or molecules that pass through the perforations. The mid-IR absorption induced by the nanoscale patterning could also have function in IR modulation or emission applications (In Preparation, 2018).

(5) Polymer-nanotube conjugate chemistry

Conjugated polymers can be exploited as agents for selectively wrapping and dispersing semiconducting versus metallic nanotubes. The mechanism is poorly understood. We have discovered that the primary factor governing semiconducting purity after sorting is the concentration of polymer in free solution as the tubes are wrapped during sonication. Our data indicate that at low polymer concentration, the resulting purity of semiconducting tubes may be as high as 99.999% (one metallic tube per 100,000) versus 66% prior to sorting (J. Phys. Chem. Lett. 2014). We have also collaborated with the lab of Padma Gopalan to develop an approach to remove polymer wrappers from nanotube surfaces (ACS Nano 2015) and to create polymer wrappers that are degradable and removable after thin film deposition (ACS Appl.

Training Opportunities: The graduate students and post-docs who have participated in this project have received technical training and gained meaningful practical experience with a variety of techniques including scanning electron microscopy, polymer wrapping of carbon nanotubes (ultrasonication, ultracentrifugation, solvent exchanges), floating evaporative self-assembly for aligning nanotubes, nanofabrication and electron beam lithography, field effect transistor fabrication and design, electrical transport measurements, optical absorption spectroscopy, plasmonics, knowledge of the photophysical properties of excitonic semiconductors, cleanroom processing, infrared spectroscopy, large dataset analysis using the software Matlab and Origin, and the thermal evaporation of metals and small molecule thin films, among other techniques. Presentations are given by researchers at individual or group meetings. Students learn project management, communication, and multitasking skills.

Results Dissemination: In addition to journal publications, our results were disseminated at 40 or more research presentations at major conferences, university seminars, and occasionally to corporations/industry.

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Honors and Awards: * Arnold: Electrochemical Society (ECS) Nanocarbons Division Early Career Award (2018) *
Note the ECS Nanocarbons division is the premier professional society entity in the field of nanocarbon materials research, having been formed in the beginning days of fullerene research in the early 1990's.

* Arnold: U.S. runner-up in the U.S. Department of State ASPIRE Competition (2017)

* Arnold: UW-Madison Romnes Faculty Fellowship (2017)

* Arnold: Invited to and voted into: Executive Committee of the Nanocarbons Division of the Electrochemical Society (2016 – current)

* Arnold: Honored Instructor Award, UW-Madison University Housing (2016)

* Gerald Brady (Fellowship student): Best student presentation award at the Carbon 2016 Conference for his oral presentation entitled "High current per tube in carbon nanotube array field effect transistors" on research partially supported by this award.

* Arnold: Harvey D. Spangler Faculty Fellowship, UW-Madison (2015)

* Arnold: UW-Madison Vilas Associates Award (2015)

* Arnold: National Science Foundation CAREER Award (2014)

* Arnold: Center for Education Opportunity, UW-Madison, Dr. Brenda Pfaehler Award of Excellence (2013)

* Arnold: American Chemical Society (ACS) Arthur K. Doolittle Award in Polymeric Materials Science and Engineering (2012) Note: Highly competitive & awarded to only 2 presenters per year at ACS.

Protocol Activity Status:

Technology Transfer: Arnold, M. S.; Xu, F., U.S. Patent No. 8,987,707: Stretchable transistors with buckled carbon nanotube films as conducting channels, Mar 24, 2015

PARTICIPANTS:

Participant Type: PD/PI

Participant: Michael Person months = 5 months Arnold

Person Months Worked: 5.00

Funding Support:

Project Contribution:

International Collaboration:

International Travel:

National Academy Member: N

Other Collaborators:

Participant Type: Postdoctoral (scholar, fellow or other postdoctoral position)

Participant: Nathaniel Person months = 3 months Safron

Person Months Worked: 3.00

Funding Support:

Project Contribution:

International Collaboration:

International Travel:

National Academy Member: N

Other Collaborators:

Participant Type: Graduate Student (research assistant)

Participant: Matthew Person months = 54 months Shea

Person Months Worked: 15.00

Funding Support:

Project Contribution:

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as of 09-Jan-2018

International Collaboration:
International Travel:
National Academy Member: N
Other Collaborators:

Participant Type: Graduate Student (research assistant)
Participant: Meng-Yin Person months = 19 months Wu
Person Months Worked: 15.00 **Funding Support:**
Project Contribution:
International Collaboration:
International Travel:
National Academy Member: N
Other Collaborators:

Participant Type: Graduate Student (research assistant)
Participant: Jialiang Person months = 2 months Wang
Person Months Worked: 2.00 **Funding Support:**
Project Contribution:
International Collaboration:
International Travel:
National Academy Member: N
Other Collaborators:

Participant Type: Graduate Student (research assistant)
Participant: Dominick Person months = 3 months Bindl
Person Months Worked: 3.00 **Funding Support:**
Project Contribution:
International Collaboration:
International Travel:
National Academy Member: N
Other Collaborators:

Participant Type: Graduate Student (research assistant)
Participant: Amir Person months = 12 months Mashal
Person Months Worked: 12.00 **Funding Support:**
Project Contribution:
International Collaboration:
International Travel:
National Academy Member: N
Other Collaborators:

Participant Type: Graduate Student (research assistant)
Participant: Chenghao Person months = 16 months Wan
Person Months Worked: 15.00 **Funding Support:**
Project Contribution:
International Collaboration:
International Travel:
National Academy Member: N
Other Collaborators:

Participant Type: Postdoctoral (scholar, fellow or other postdoctoral position)
Participant: Robert Person months = 4 months Jacobberger
Person Months Worked: 4.00 **Funding Support:**

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as of 09-Jan-2018

Project Contribution:
International Collaboration:
International Travel:
National Academy Member: N
Other Collaborators:

Participant Type: Postdoctoral (scholar, fellow or other postdoctoral position)

Participant: Feng Person months = 8 months Xu

Person Months Worked: 8.00

Funding Support:

Project Contribution:
International Collaboration:
International Travel:
National Academy Member: N
Other Collaborators:

Participant Type: Postdoctoral (scholar, fellow or other postdoctoral position)

Participant: Naechul Person months = 5 months Shin

Person Months Worked: 5.00

Funding Support:

Project Contribution:
International Collaboration:
International Travel:
National Academy Member: N
Other Collaborators:

Participant Type: Undergraduate Student

Participant: Tou Person months = 2 months Chang

Person Months Worked: 2.00

Funding Support:

Project Contribution:
International Collaboration:
International Travel:
National Academy Member: N
Other Collaborators:

Participant Type: Postdoctoral (scholar, fellow or other postdoctoral position)

Participant: Yumin Person months = 2 months Ye

Person Months Worked: 2.00

Funding Support:

Project Contribution:
International Collaboration:
International Travel:
National Academy Member: N
Other Collaborators:

ARTICLES:

RPPR Final Report
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Publication Type: Journal Article Peer Reviewed: Y **Publication Status:** 1-Published

Journal: Chemical Physics

Publication Identifier Type: DOI

Publication Identifier: 10.1016/j.chemphys.2012.08.001

Volume: 0 Issue: 0

First Page #: 0

Date Submitted:

Date Published:

Publication Location:

Article Title: Enhancing extraction of photogenerated excitons from semiconducting carbon nanotube films as photocurrent

Authors:

Keywords: Carbon nanotube; Exciton; Diffusion; Photovoltaic; Photodetector; Near infrared

Abstract: We study the effect of residual polymer on exciton transport and the external quantum efficiency (EQE) of photocurrent generation in thin film semiconducting single walled carbon nanotube (s-SWCNT)/C60 heterojunction diodes. Specifically, increasing the s-SWCNT film content from 22% to 43% increases peak EQE from absorption by s-SWCNTs from 15% to 23%. We monitor intertube exciton energy transfer via steady state photoluminescence spectroscopy and determine the length scale for exciton migration via s-SWCNT film thickness dependence of EQE. We observe increased intertube exciton transfer in photoluminescence spectra with increased polymer removal, and EQE-thickness dependence suggests increased intratube exciton transport along isolated pathways. Our results extend the state of the art with respect to the use of s-SWCNT thin films as photoabsorbers in photovoltaics, describe exciton migration in s-SWCNT films, and provide a framework for the design of high efficiency s-SWCNT photovolta

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Journal: Applied Physics Letters

Publication Identifier Type: DOI

Publication Identifier: 10.1063/1.4811359

Volume: 102 Issue: 24

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Publication Location:

Article Title: 1% solar cells derived from ultrathin carbon nanotube photoabsorbing films

Authors:

Keywords: carbon nanotubes, energy gap, fullerenes, nanotube devices, solar cells

Abstract: Using a carbon nanotube photoabsorbing film <5 nm in thickness, we demonstrate a 1% solar cell. Specifically, polymer wrapped, highly monochiral (7, 5) nanotubes are implemented in a bilayered heterojunction with acceptor C60. The nanotubes drive 63% of the conversion, several times stronger than previously demonstrated. Peak external quantum efficiency (QE) of 43% at the nanotube bandgap (1055 nm) and power conversion efficiency of 0.95% and 1.02% at 1.0 and 1.5 suns, respectively, are achieved. The high internal QE from the ultrathin layers suggests that nanostructured or multijunction cells exploiting multiple nanotube layers will be many times more efficient.

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Journal: Physical Chemistry Chemical Physics

Publication Identifier Type: DOI

Publication Identifier: 10.1039/c3cp52752b

Volume: 15

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Date Published:

Publication Location:

Article Title: Recent developments in the photophysics of single-walled carbon nanotubes for their use as active and passive material elements in thin film photovoltaics

Authors:

Keywords: Carbon nanotube photovoltaic photophysics solar cell perspective

Abstract: The search for environmentally clean energy sources has spawned a wave of research into the use of carbon nanomaterials for photovoltaic applications. In particular, research using semiconducting single-walled carbon nanotubes has undergone dramatic transformations due to the availability of high quality samples through colloidal separation techniques. This has led to breakthrough discoveries on how energy and charge transport occurs in these materials and points to applications in energy harvesting. We present a review of the relevant photophysics of carbon nanotubes that dictate processes important for integration as active and passive material elements in thin film photovoltaics. Fundamental processes ranging from light absorption and internal conversion to exciton transport and dissociation are discussed in detail from both a spectroscopic and a device perspective. We also give a perspective on the future of these fascinating materials to be used as active and passive material elements.

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Journal: Small

Publication Identifier Type: DOI

Publication Identifier: 10.1002/smll.201400696

Volume: 10

Issue: 16

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Date Submitted:

Date Published:

Publication Location:

Article Title: Semiconducting Carbon Nanotube Aerogel Bulk Heterojunction Solar Cells

Authors:

Keywords: photovoltaic;exciton;blend;nanocomposite;near-infrared

Abstract: Using a novel two-step fabrication scheme, we create highly semiconducting-enriched single-walled carbon nanotube (sSWNT) bulk heterojunctions (BHJs) by first creating highly porous interconnected sSWNT aerogels (sSWNT-AEROs), followed by back-filling the pores with [6,6]-phenyl-C71-butyric acid methyl ester (PC71BM). We demonstrate sSWNT-AERO structures with density as low as 2.5 mg cm⁻³, porosity as high as 99.8%, and diameter of sSWNT fibers \approx 10 nm. Upon spin coating with PC71BM, the resulting sSWNT-AERO-PC71BM nanocomposites exhibit highly quenched sSWNT photoluminescence, which is attributed to the large interfacial area between the sSWNT and PC71BM phases, and an appropriate sSWNT fiber diameter that matches the inter-sSWNT exciton migration length. Employing the sSWNT-AERO-PC71BM BHJ structure, we report optimized solar cells with a power conversion efficiency of 1.7%, which is exceptional among polymer-like solar cells in which sSWNTs are designed to replace either the polymer

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Journal: Nano Letters

Publication Identifier Type: DOI

Publication Identifier: 10.1021/nl403941a

Volume: 14

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Date Submitted:

Date Published:

Publication Location:

Article Title: Highly Stretchable Carbon Nanotube Transistors with Ion Gel Gate Dielectrics

Authors:

Keywords: Carbon nanotube; transistor; stretchable electronics; ion gel gate dielectric

Abstract: Field-effect transistors (FETs) that are stretchable up to 50% without appreciable degradation in performance are demonstrated. The FETs are based on buckled thin films of polyfluorene-wrapped semiconducting single-walled carbon nanotubes (CNTs) as the channel, a flexible ion gel as the dielectric, and buckled metal films as electrodes. The buckling of the CNT film enables the high degree of stretchability while the flexible nature of the ion gel allows it to maintain a high quality interface with the CNTs during stretching. An excellent on/off ratio of $>10^4$, a field-effect mobility of $10 \text{ cm}^2 \cdot \text{V}^{-1} \cdot \text{s}^{-1}$, and a low operating voltage of $<2 \text{ V}$ are achieved over repeated mechanical cycling, with further strain accommodation possible. Deformable FETs are expected to facilitate new technologies like stretchable displays, conformal devices, and electronic skins.

Distribution Statement: 1-Approved for public release; distribution is unlimited.

Acknowledged Federal Support:

PATENTS:

Intellectual Property Type: Patent

Date Received: **03-Jan-2018**

Patent Title: Stretchable transistors with buckled carbon nanotube films as conducting channels

Patent Abstract: Thin-film transistors comprising buckled films comprising carbon nanotubes as the conductive cl

Patent Number: 8987707

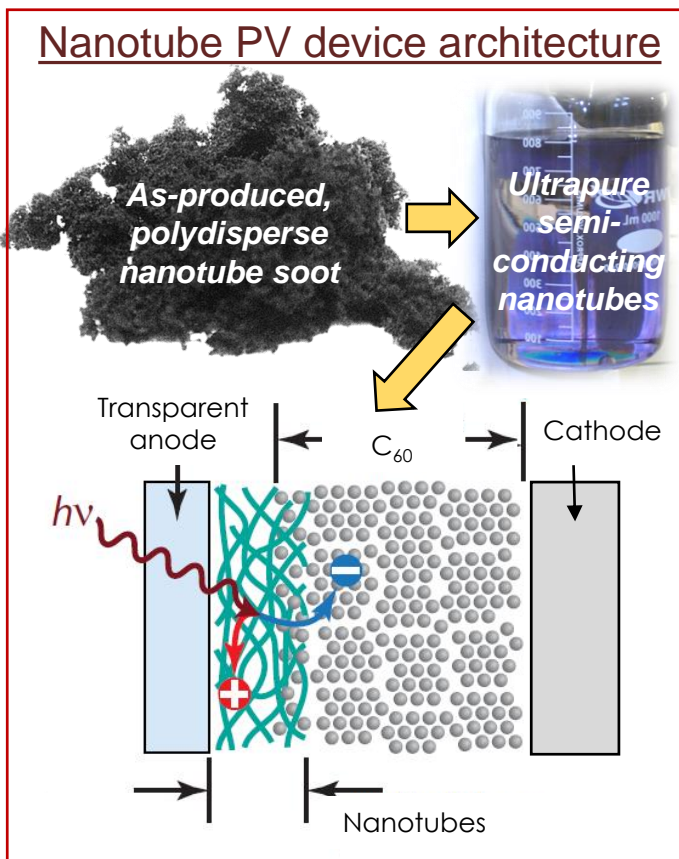
Patent Country: USA

Application Date: 20-Aug-2013

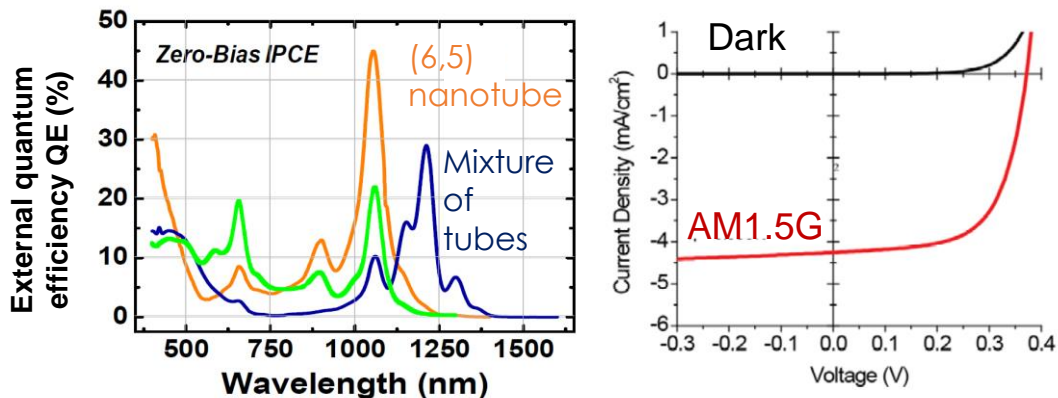
Application Status: 3

Date Issued: 24-Mar-2015

Fig. 1. Semiconducting carbon nanotube-based photovoltaic solar cells and photodetectors



Characteristics using ultrathin (5 nm) nanotube photoabsorbing layers



- 1% solar and 7% monochromatic power efficiency, even through only a few % of the solar flux is absorbed.
- The peak external and internal QE at the nanotube bandgap (1055 nm) are 43% and >75%, respectively.
- Specific detectivity (D^*) is 1×10^{12} Jones at 1055 nm.
- Higher efficiency predicted by eliminating exciton quenching sites to achieve longer-range exciton migration.

Fig. 2. Carbon nanotube-enabled stretchable field-effect transistors (FETs)

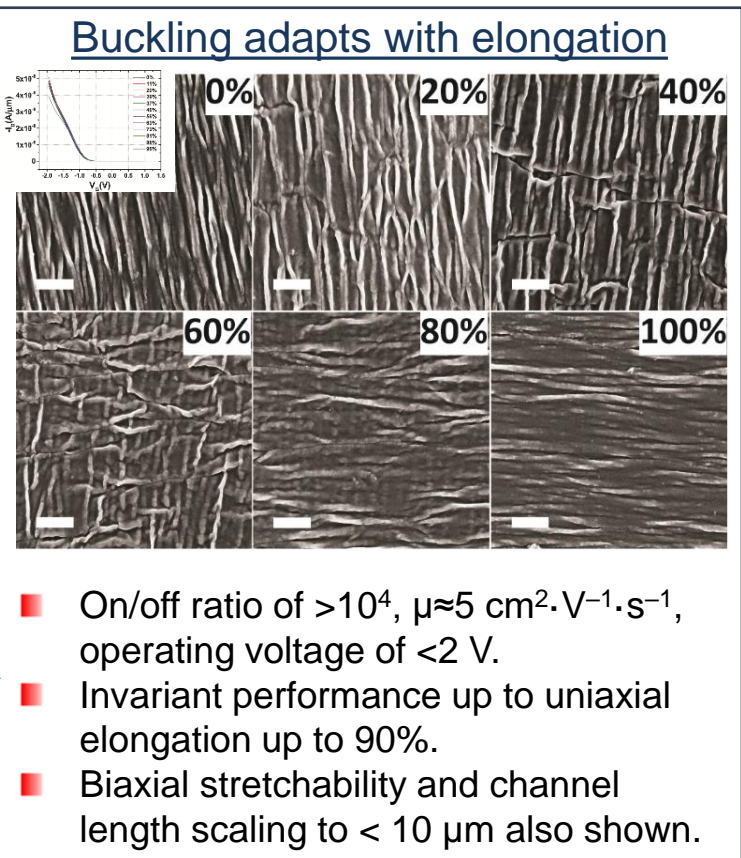
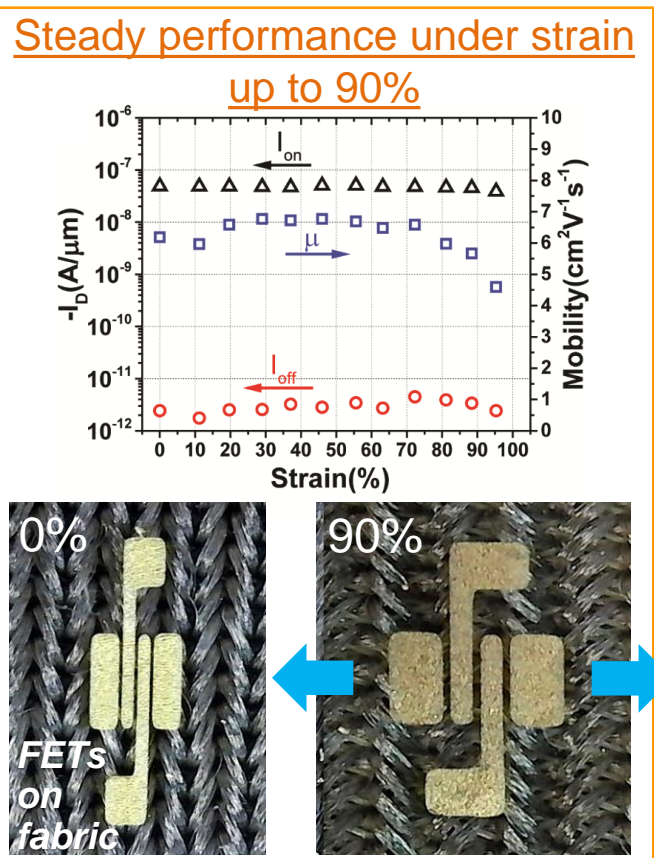
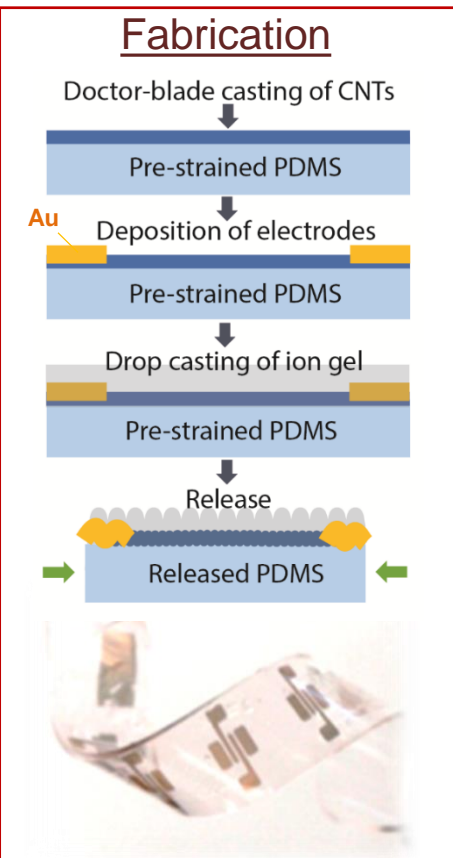


Fig. 3. Nanostructured graphene plasmonics

